

Switchmode Full Plastic Dual Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. The proprietary barrier technology allows for reliable operation up to 150°C junction temperature. Typical applications are in switching Mode Power Supplies such as adaptors, DC/DC converters, freewheeling and polarity protection diodes.

Features

- *Low Forward Voltage.
- *Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- *Low Power Loss & High efficiency.
- * High Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- *Pb free
- * In compliance with EU RoHs directives



MAXIMUM RATINGS

Characteristic	Symbol	S30T100F	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	100	V
RMS Reverse Voltage	V _{R(RMS)}	70	V
Average Rectifier Forward Current $$ (per diode) Total Device (Rated V_R),	I _{F(AV)}	15 30	Α
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	30	Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-ware, single phase, 60Hz)	I _{FSM}	320	Α
Operating and Storage Junction Temperature Range	T_J , T_{stg}	-65 to +150	$^{\circ}\!\mathbb{C}$

THERMAL RESISTANCES

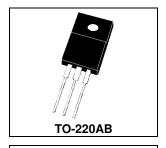
Typical Thermal Resistance junction to case	$R_{\theta jc}$	4.8	°C/w
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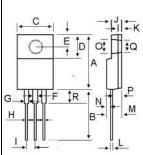
ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage (per diode) (I_F =15.0 Amp T_C = 25 $^{\circ}$ C) (I_F =15.0 Amp T_C = 125 $^{\circ}$ C)	V _F		0.68 0.62	0.73	>
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	I _R		15 15	50 	uA mA

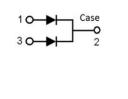
SCHOTTKY BARRIER RECTIFIERS

30 AMPERES 100 VOLTS

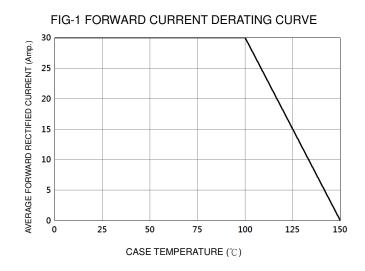


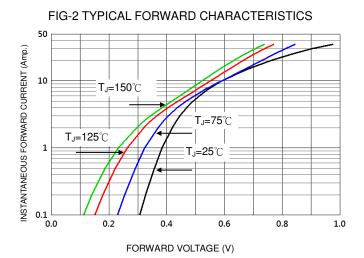


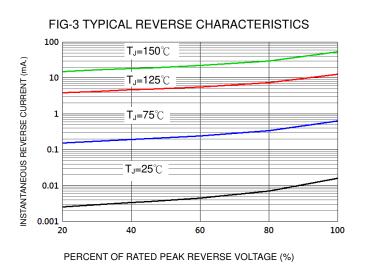
	NAIL LINA	ETERS
DIM		
	MIN	MAX
Α	14.80	16.10
В	12.65	14.40
С	9.70	10.36
D	4.60	6.80
Е	2.50	3.50
F	0.90	1.45
G	0.90	1.45
Н	0.50	0.90
- 1	2.40	2.70
J	2.34	3.30
K	0.55	1.30
L	0.36	0.80
М	4.20	4.90
N	1.10	1.80
0	2.90	3.50
Р	2.30	3.15
Q	2.90	3.50
Ř	2.80	4.85

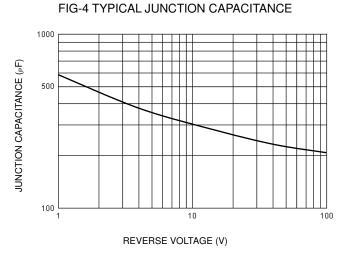


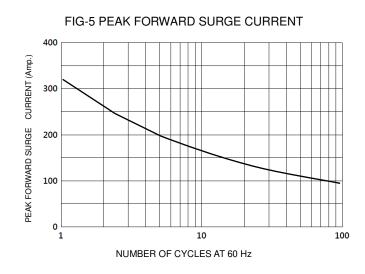














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